Thyristor Semiconductor Device - Page 1 of 1



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In	closure Material:
М	etal
0	verall Length:
0.	260 inches
Te	erminal Length:
1.	500 inches
0	verall Diameter:
0.	370 inches
In	ternal Configuration:
Ju	inction contact
Jo	int Electronic Device Engineering Council/jedec/case Outline Designation:
Тс	p-5
Μ	ounting Method:
Te	erminal
Te	erminal Circle Diameter:
0.	200 inches
Fe	eatures Provided:
H	ermetically sealed case
Se	emiconductor Material:
Si	licon
V	oltage Rating In Volts Per Characteristic:
50	0.0 repetitive peak off-state voltage
C	urrent Rating Per Characteristic:
1.	00 amperes forward current, total rms horsepower metric
М	aximum Operating Tempurature Per Measurement Point:
12	25.0 degrees celsius case
S	pecial Features:
Ju	nction pattern arrangement: pnpnp
Te	erminal Type And Quantity:
3	uninsulated wire lead
S	pecification Data:
80	131-release3265 professional/industrial association specification
SI	nelf Life:
N/	a
U	nit Of Measure:
D	emilitarization:
N	
Fi	ig:
	110a0